





## SD103BWSA SCHOTTKY BARRIER DIODE



#### **Features**

- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material —UL Recognition Flammability Classification 94V-O
- Green Products in Compliance with the ROHS Directive
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Schematic & Pin Configuration**



#### **Mechanical Characteristics**

- Case: SOD-323, Molded plastic
- Terminals: Plated Leads Solderable per MIL-STD-202,
  - Method 208
- Polarity: Cathode BandWeight: 0.04 grams(approx)

## Maximum Ratings @T<sub>A</sub>=25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Peak Reverse Voltage	V <sub>RRM</sub>	30	V
Average Forward Current	lo	100	mA
Power Dissipation	P <sub>D</sub>	250	mW
Power Dissipation(T <sub>L</sub> = 25°C)	P <sub>D</sub>	833	mW
Peak Forward Surge Current (tp=8.3ms)	IFSM	750	mA
Operating Junction Temperature Range	TJ	-65 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	°C
Thermal Resistance	R <sub>ΘJA</sub>	500	°C/W
Thermal Resistance	R <sub>OJL</sub>	150	°C/W

Note: 1. Valid provided that terminals are kept at ambient temperature.





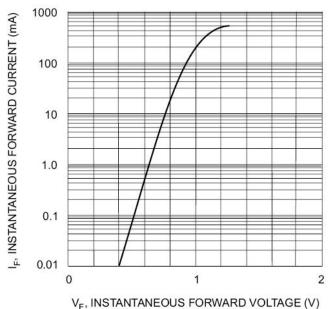


# Electrical Characteristics @T<sub>A</sub>=25°C unless otherwise specified

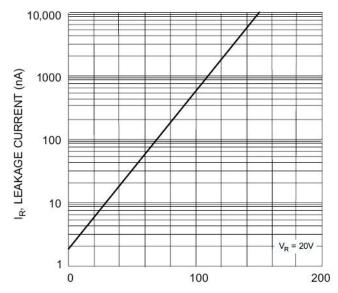
Characteristics	Symbol	Condition	Min	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F</sub>	$@I_F = 50mA, T_A = 25^{\circ}C$	-	-	0.55	V
		$@I_F = 100 \text{mA}, T_A = 25 ^{\circ}\text{C}$	-	-	0.80	
Reverse Recovery Voltage*	$V_{BR}$	@I <sub>F</sub> = 100uA	30	-	-	V
Reverse Current*	I <sub>R</sub>	@V <sub>R</sub> = 25V, T <sub>J</sub> = 25 °C	-	-	10	uA
Typical Junction Capacitance	Cj	@V <sub>R</sub> =10.0 V, Tc=25°C, f <sub>SIG</sub> = 1MHz	-	7.0	-	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

# **Ratings and Characteristics Curves**



INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 1 Forward Characteristics



 $\label{eq:tj} \textbf{T}_{j}, \, \text{JUNCTION TEMPERATURE (°C)} \\ \text{Fig. 2 Leakage Current vs Junction Temperature}$ 

<sup>•</sup> China - Germany - Korea - Singapore - United States •

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •







## **Ordering Information**

Device	Package	Shipping
SD103BWSA	SOD-323 (Pb-Free)	3000pcs / reel

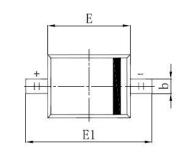
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

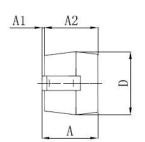
# **Marking Diagram**

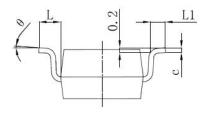


S1 = Marking Code

## **Mechanical Dimensions SOD-323**

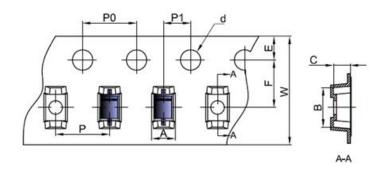






OVMDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	-	1.000	-	0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
Е	1.600	1.800	0.063	0.071	
E1	2.500	2.700	0.098	0.106	
L	0.475 REF.		0.019 REF.		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

# **Carrier Tape Specification SOD-323**



SYMB	Millimeters		
OL	Min.	Max.	
В	2.85	2.95	
С	1.20	1.30	
d	1.40	1.60	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

- China Germany Korea Singapore United States
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